CONDUCTIVE MEMORY DEVICE WITH BARRIER ELECTRODES
'Darrell Rinerson; Steven W. Longcor; Steve Kuo-Ren Hsia; Wayne Kinney; Edmond R. Ward and Christophe J. Chevallier
Prepared by Beyer Weaver & Thomas, LLP, (650) 961-8300, Ref: UNTYP024; Contact Morgan Malino

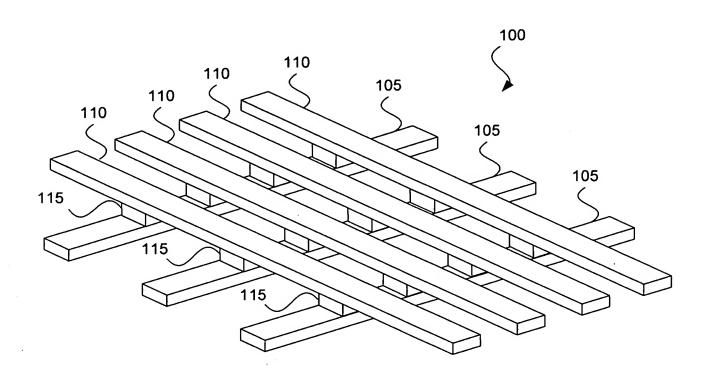


FIG. 1

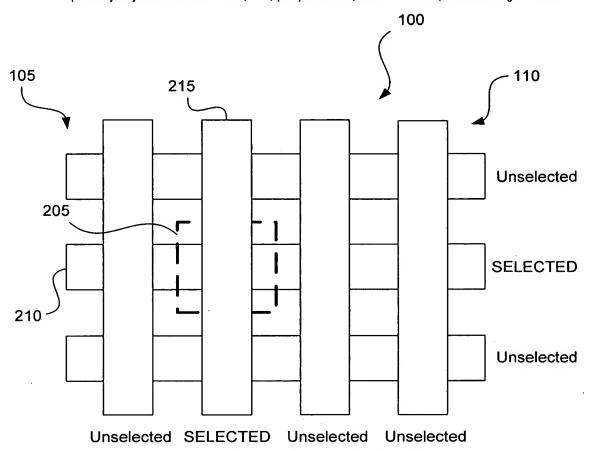
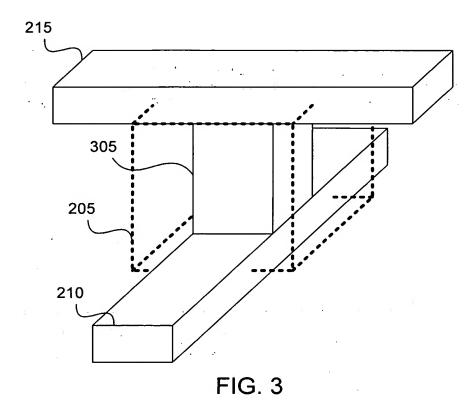


FIG. 2

CONDUCTIVE MEMORY DEVICE WITH BARRIER ELECTRODES

Darrell Rinerson; Steven W. Longcor; Steve Kuo-Ren Hsia; Wayne Kinney; Edmond R. Ward and Christophe J. Chevallier Prepared by Beyer Weaver & Thomas, LLP, (650) 961-8300, Ref: UNTYP024; Contact Morgan Malino



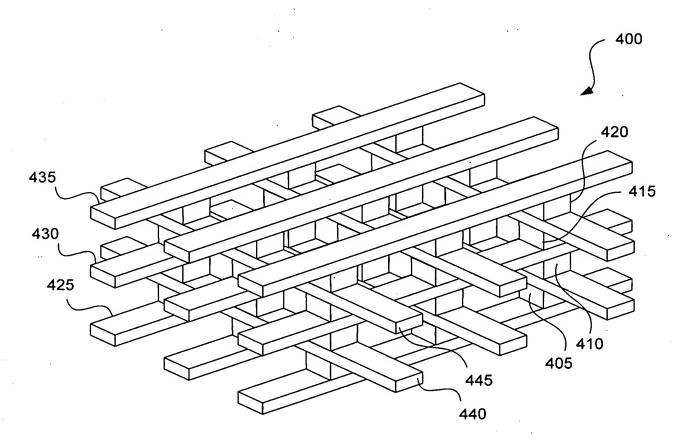


FIG. 4

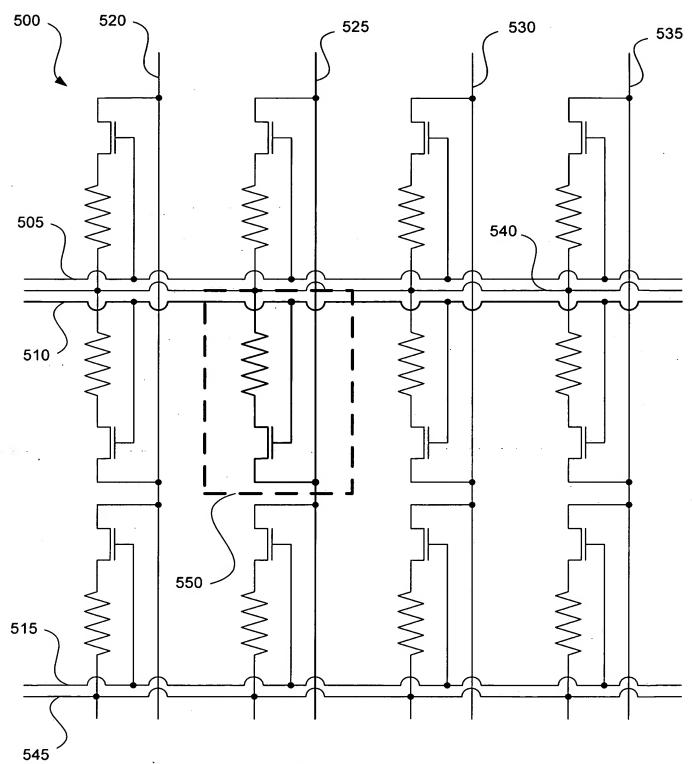


FIG. 5

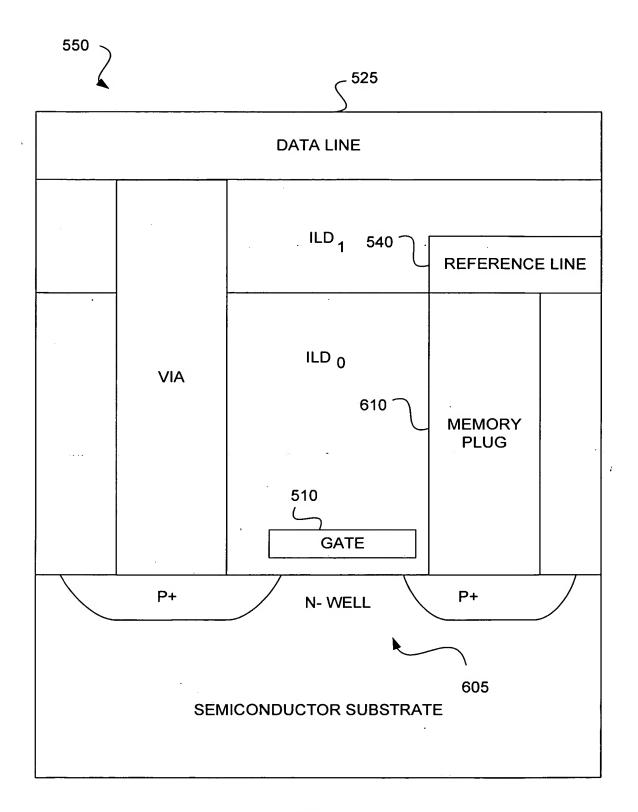
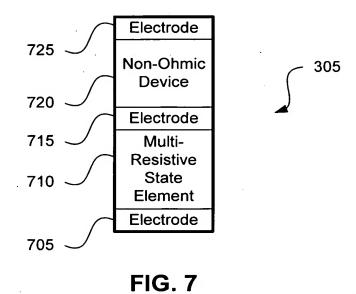


FIG. 6



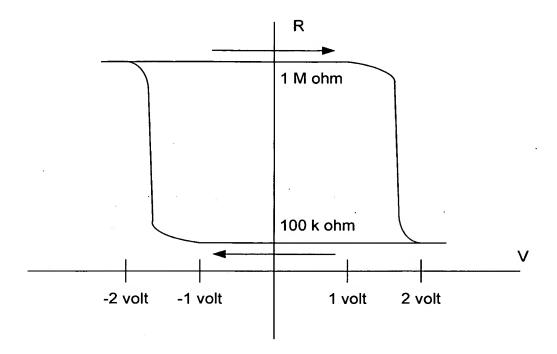


FIG. 8A

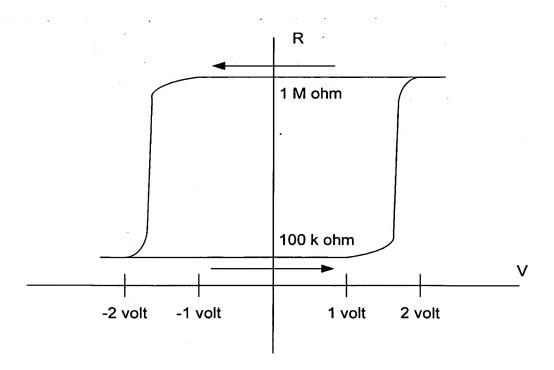


FIG. 8B

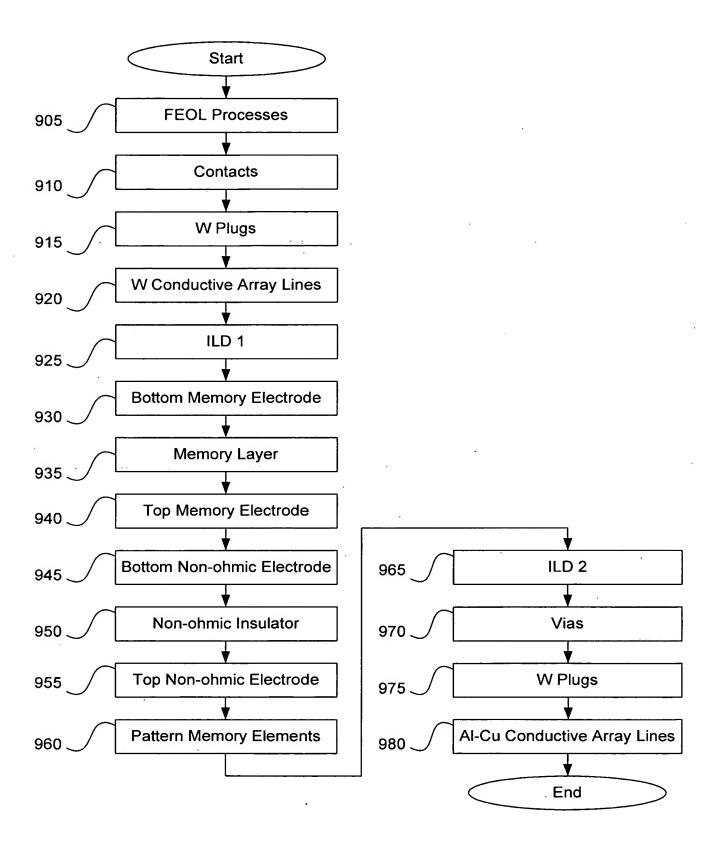
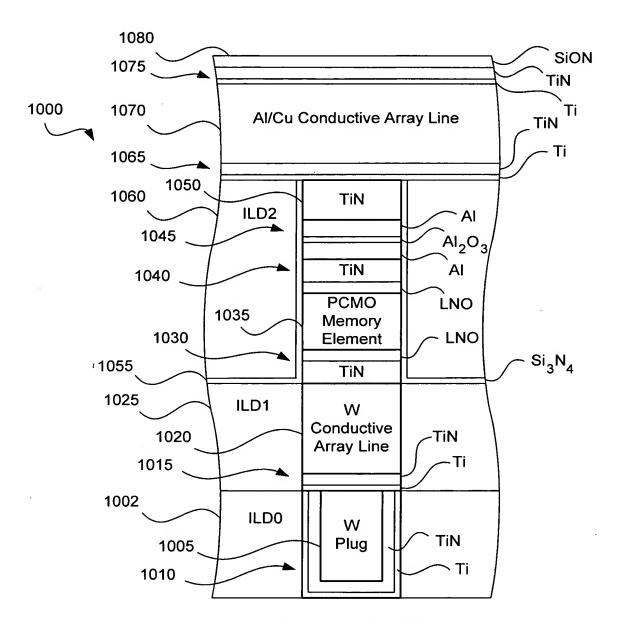


FIG. 9



Semiconductor Wafer

FIG. 10

Darrell Rinerson; Steven W. Longcor; Steve Kuo-Ren Hsia; Wayne Kinney; Edmond R. Ward and Christophe J. Chevallier Prepared by Beyer Weaver & Thomas, LLP, (650) 961-8300, Ref: UNTYP024; Contact Morgan Malino

1100

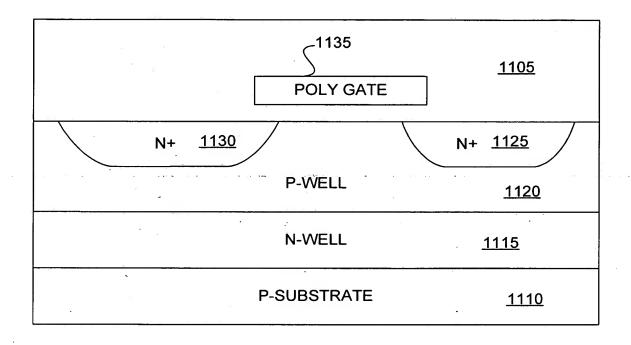


FIG. 11

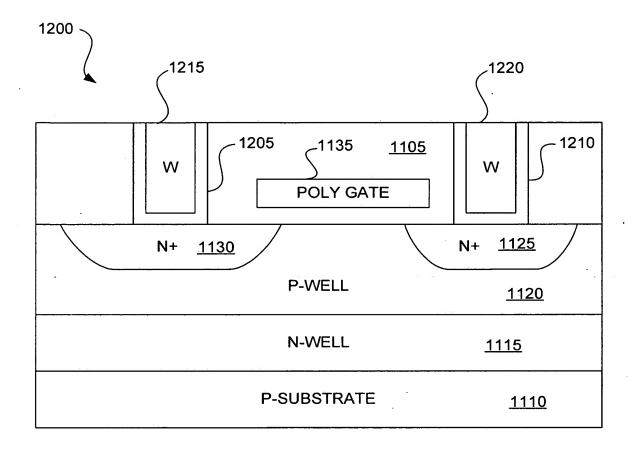


FIG. 12

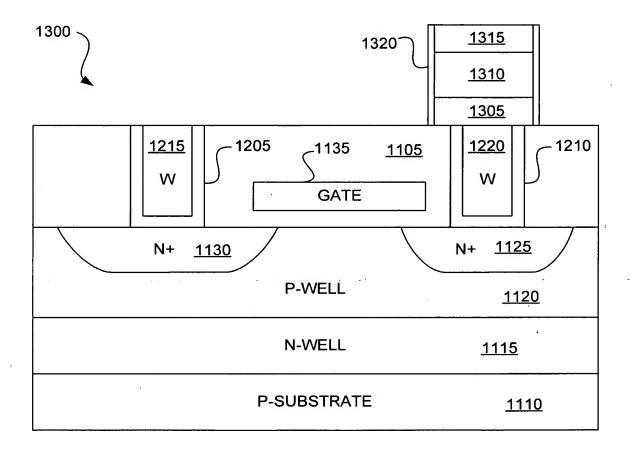


FIG. 13



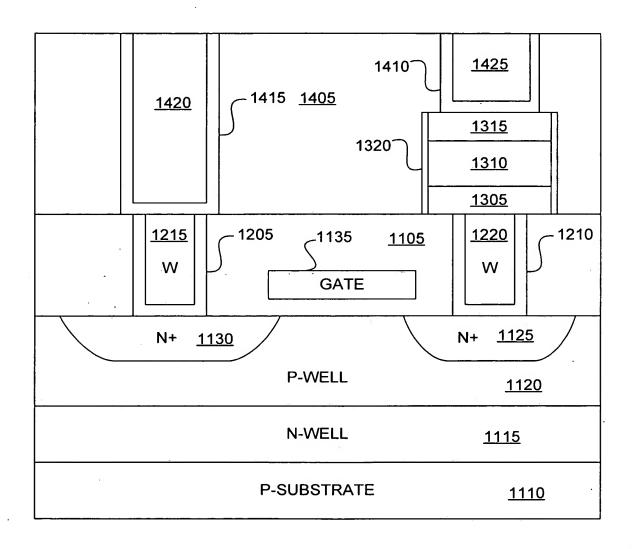


FIG. 14



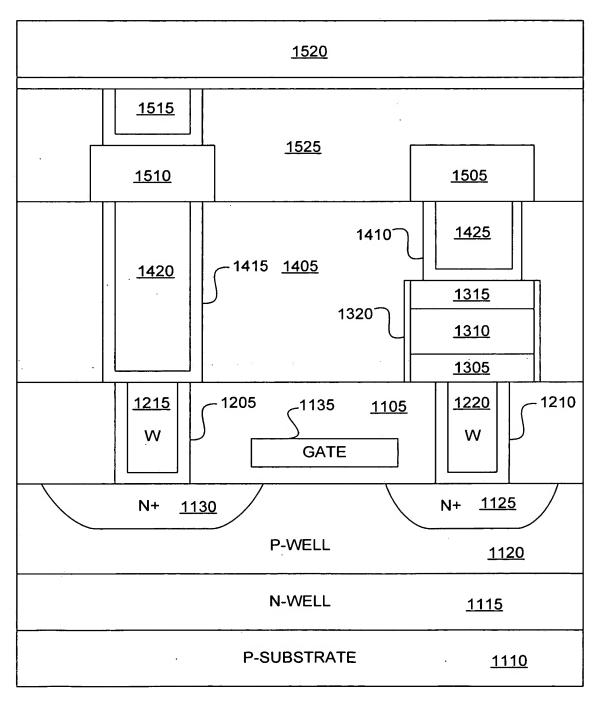


FIG. 15